

REMARKS

Favorable consideration and allowance of the claims of the present application are respectfully requested. No amendments to the claims or specification are being made herein.

In the present Official Action, Claims 1-20 which are present in the above-captioned application have been subjected to a restriction under 35 U.S.C. §121 as follows:

- I. Claims 1-11, drawn to a semiconductor memory structure, classified in Class 438, subclass 243+; and
- II. Claims 12-20, drawn to a method for forming a semiconductor memory structure, classified in Class 257, subclass 296+.

As indicated, and in order to be fully responsive to the restriction requirement imposed in the present Official Action, applicants provisionally elect, without traverse, to prosecute the subject matter of Group I, i.e., Claims 1-11, and reserve the right to file one or more divisional applications directed to the non-elected subject matter in this application, i.e., Claims 12-20.

Wherefore, consideration and allowance of the claims of the present application are respectfully requested.

Respectfully submitted,



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